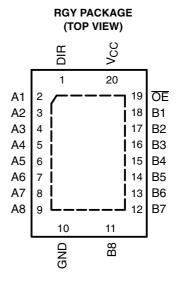
- Supports Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Supports Unregulated Battery Operation Down to 2.7 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C

	DB, DW, NS, OR PW PACKAGE (TOP VIEW)										
DIR [ 1 20 ] V <sub>CC</sub> A1 [ 2 19 ] OE A2 [ 3 18 ] B1 A3 [ 4 17 ] B2 A4 [ 5 16 ] B3 A5 [ 6 15 ] B4 A6 [ 7 14 ] B5 A7 [ 8 13 ] B6 A8 [ 9 12 ] B7 GND [ 10 11 ] B8	DIR [ A1 [ A2 [ A3 [ A4 [ A5 [ A7 [ A8 [	1 2 3 4 5 6 7 8 9	20 19 18 17 16 15 14 13	OE B1 B2 B3 B4 B5 B6							

- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



#### description/ordering information

This octal bus transceiver is designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

The SN74LVT245B is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the device so the buses are effectively isolated.

T <sub>A</sub>	PACKAGE	t	ORDERABLE PART NUMBER	TOP-SIDE MARKING					
	QFN – RGY	Tape and reel	SN74LVT245BRGYR	LX245B					
		Tube	SN74LVT245BDW						
	SOIC – DW	Tape and reel	SN74LVT245BDWR	LVT245B					
	SOP – NS	Tape and reel	SN74LVT245BNSR	LVT245B					
–40°C to 85°C	SSOP – DB	Tape and reel	SN74LVT245BDBR	LX245B					
	T0000 DW/	Tube	SN74LVT245BPW						
	TSSOP – PW	Tape and reel	SN74LVT245BPWR	LX245B					
	VFBGA – GQN	Tana and real	SN74LVT245BGQNR						
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVT245BZQNR	LX245B					

#### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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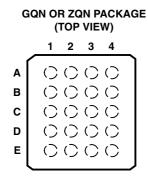
1

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### description/ordering information (continued)

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.



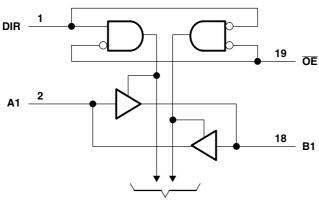
#### terminal assignments

	1	2	3	4
Α	A1	DIR	V <sub>CC</sub>	ŌĒ
в	A3	B2	A2	B1
С	A5	A4	B4	B3
D	A7	B6	A6	B5
Е	GND	A8	B8	B7

#### **FUNCTION TABLE**

INP	UTS	
ŌE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Х	Isolation

logic diagram (positive logic)



**To Seven Other Channels** 

Pin numbers shown are for the DB, DW, NS, PW, and RGY packages.



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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub>	-0.5 V to 4.6 V
Input voltage range, $V_{\rm I}$ (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, $V_{\Omega}$ (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, $V_O$ (see Note 1)	
Current into any output in the low state, $I_0$	
Current into any output in the high state, I <sub>O</sub> (see Note 2)	
Input clamp current, $I_{IK}$ (V <sub>I</sub> < 0)	
Output clamp current, $I_{OK}$ ( $V_O < 0$ )	
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package	
(see Note 3): DW package	
(see Note 3): GQN/ZQN package	
(see Note 3): NS package	
(see Note 3): PW package	
(see Note 4): RGY package	
Storage temperature range, T <sub>sta</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and  $V_{O} > V_{CC}$ .
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.

#### recommended operating conditions (see Note 5)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.7	3.6	V
V <sub>IH</sub>	High-level input voltage		2		V
V <sub>IL</sub>	Low-level input voltage			0.8	V
VI	Input voltage			5.5	V
I <sub>OH</sub>	High-level output current			-32	mA
I <sub>OL</sub>	Low-level output current			64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

NOTE 5: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TES	T CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT	
V <sub>IK</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>I</sub> = -18 mA			-1.2	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V,	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> -0.2				
V <sub>OH</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>OH</sub> = -8 mA	2.4			v	
		V <sub>CC</sub> = 3 V,	I <sub>OH</sub> = -32 mA	2				
		N 07V	I <sub>OL</sub> = 100 μA			0.2		
		V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 24 mA			0.5		
V <sub>OL</sub>			I <sub>OL</sub> = 16 mA			0.4	V	
		$V_{CC} = 3 V$	I <sub>OL</sub> = 32 mA		0.5			
			I <sub>OL</sub> = 64 mA			0.55		
	Oratalianta	V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC}$ or GND			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V	10			l	
l <sub>i</sub>			V <sub>I</sub> = 5.5 V			20	μA	
	A or B ports <sup>‡</sup>	V <sub>CC</sub> = 3.6 V	$V_I = V_{CC}$		1			
			$V_{I} = 0$			-5		
I <sub>off</sub>		$V_{CC} = 0,$	$V_{I}$ or $V_{O} = 0$ to 4.5 V			±100	μA	
I <sub>OZH</sub>		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 3 V			5	μA	
I <sub>OZL</sub>		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 0.5 V			-5	μA	
I <sub>OZPU</sub>		$V_{CC}$ = 0 to 1.5 V, $V_O$ = 0.5 V	to 3 V, $\overline{OE}$ = don't care			±100	μA	
I <sub>OZPD</sub>		$V_{CC}$ = 1.5 V to 0, $V_{O}$ = 0.5 V	to 3 V, $\overline{OE}$ = don't care			±100	μA	
		V <sub>CC</sub> = 3.6 V,	Outputs high			0.19		
Icc		$I_{O} = 0,$	Outputs low	5			mA	
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19		
∆l <sub>CC</sub> §		$V_{CC}$ = 3 V to 3.6 V, One input Other inputs at $V_{CC}$ or GND	t at V <sub>CC</sub> – 0.6 V,			0.2	mA	
Ci		V <sub>I</sub> = 3 V or 0			4		pF	
Cio		$V_0 = 3 V \text{ or } 0$			9		pF	

 $^{\dagger}$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

<sup>‡</sup> Unused terminals are at  $V_{CC}$  or GND.

§ This is the increase in supply current for each input that is at the specified TTL-voltage level, rather than V<sub>CC</sub> or GND.

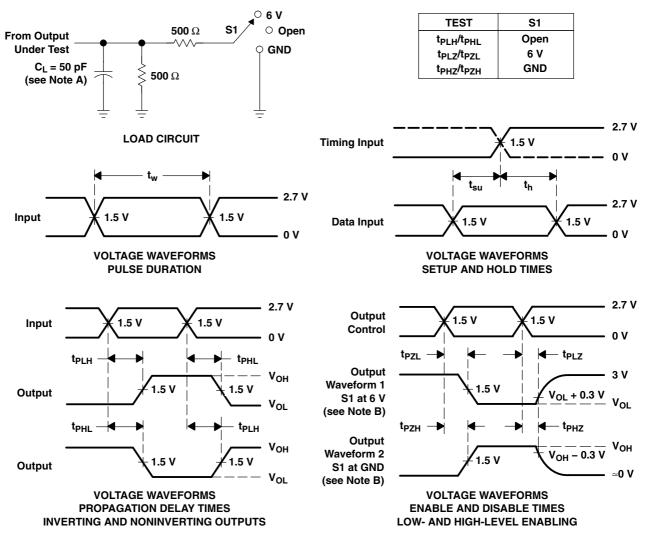
switching characteristics over recommended operating free-air temperature range,  $C_L$  = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	vo	<sub>CC</sub> = 3.3 ' ± 0.3 V	V	V <sub>CC</sub> =	UNIT	
	(INPUT)	(OUTPUT)	MIN	TYP <sup>†</sup>	MAX	MIN	MAX	
t <sub>PLH</sub>	A av D	D er A	1.2	2.3	3.5		4	
t <sub>PHL</sub>	A or B	B or A	1.2	2.1	3.5		4	ns
t <sub>PZH</sub>	<u>AE</u>	A as D	1.3	3.2	5.5		7.1	
t <sub>PZL</sub>	ŌĒ	A or B	1.7	3.4	5.5		6.5	ns
t <sub>PHZ</sub>	<u>AE</u>	A ar D	2.2	3.5	5.9		6.5	
t <sub>PLZ</sub>	ŌĒ	A or B	2.2	3.4	5		5.1	ns

 $^{\dagger}$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.



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#### PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms





24-Aug-2018

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVT245BDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BDBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT245B	Samples
SN74LVT245BDWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT245B	Samples
SN74LVT245BDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT245B	Samples
SN74LVT245BDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT245B	Samples
SN74LVT245BDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT245B	Samples
SN74LVT245BNSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT245B	Samples
SN74LVT245BPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LX245B	Samples
SN74LVT245BRGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LX245B	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.



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<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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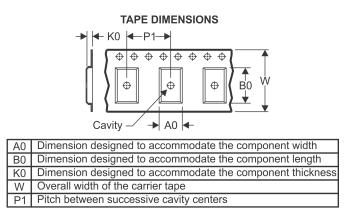
# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVT245BDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVT245BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVT245BNSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVT245BRGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

12-Jul-2018



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVT245BDBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVT245BDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVT245BNSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVT245BRGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  $\beta$ . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



## LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



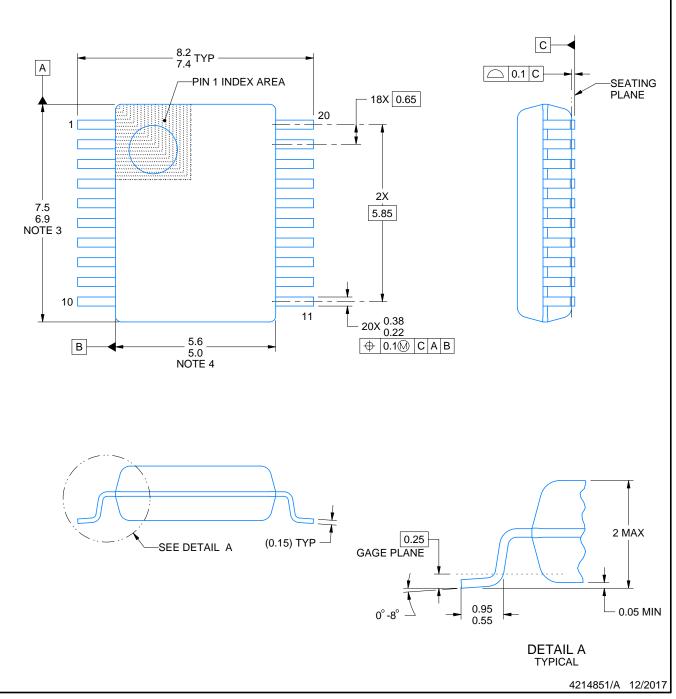
# **DB0020A**



# **PACKAGE OUTLINE**

## TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.

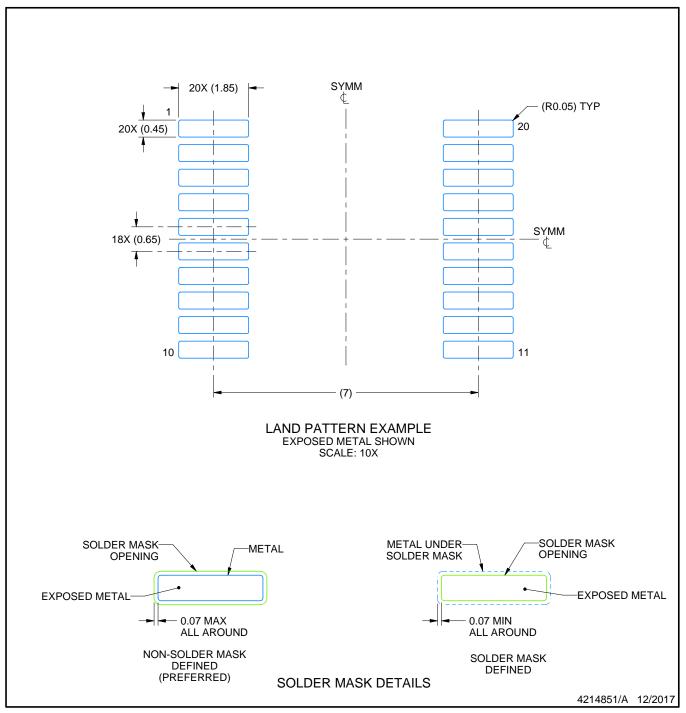


# DB0020A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

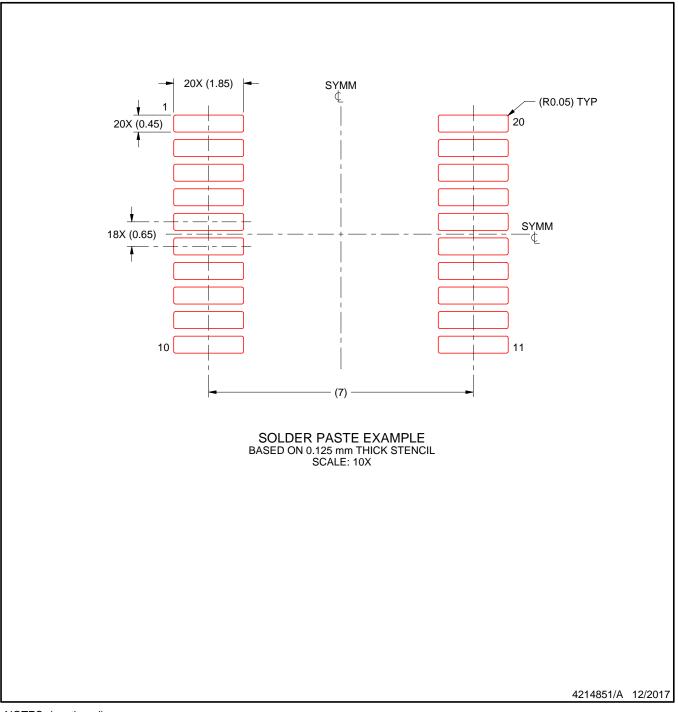


# DB0020A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **DW0020A**



# **PACKAGE OUTLINE**

### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



# DW0020A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DW0020A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



## RGY (R-PVQFN-N20)

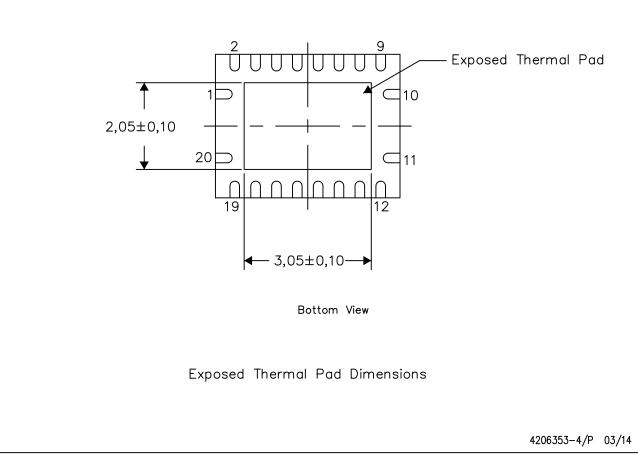
### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



#### NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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